Biochemical sensing at the surface of graphene field-effect transistors

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Abstract.

Recent research trends now offer new opportunities for developing the next generations of label-free biochemical sensors using graphene and other two-dimensional materials. While the physics of graphene transistors operated in electrolyte is well grounded, important chemical challenges still remain to be addressed, namely the impact of the chemical functionalizations of graphene on the key electrical parameters and the sensing performances. In fact, graphene – at least ideal graphene – is highly chemically inert. The functionalizations and chemical alterations of the graphene surface – both covalently and non-covalently – are crucial steps that define the sensitivity of graphene. The presence, reactivity, adsorption of gas and ions, proteins, DNA, cells and tissues on graphene have been successfully monitored with graphene. This review aims to unify most of the work done so far on biochemical sensing at the surface of a (chemically functionalized) graphene field-effect transistor and the challenges that lie ahead. We are convinced that graphene biochemical sensors hold great promises to meet the ever-increasing demand for sensitivity, especially looking at the recent progresses suggesting that the obstacle of Debye screening can be overcome.
Author description.

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![Dr. Wangyang Fu](image1.png)

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![Lin Jiang](image2.png)

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at Harvard University with Prof. George Whitesides and at TU Delft with Prof. Cees Dekker. His research interests include nanotechnology, bionanotechnology, surface and interfacial chemistry, physical and organic chemistry, materials science, biophysical chemistry, nanofluidics, and self-assembly.
This review aims to unify most of the work done so far on biochemical sensing at the surface of a (chemically functionalized) graphene field-effect transistor and the challenges that lie ahead, including the recent progresses in meeting the ever increasing demand for sensitivity by overcoming the obstacle of Debye screening.

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1. Introduction: challenges and opportunities

Ultrasensitive biosensors are opening up new opportunities for 'personalized medicine' tailored to the specific biochemistry and diagnostic of individual patients.[1, 2] While versatile detection strategies exist, the main requirements for a biosensor is that the detection is sensitive (identification of clinically relevant concentrations of biomarkers in biological samples) and selective (availability of a suitable biological recognition element).[3] Since the experimental preparation and observation of the electric field effect in graphene by the Manchester group in 2004,[4] biochemical sensing using graphene electronic devices has been actively pursued.[5-12] The sensing principle roots on a change of the electrical conductance of the graphene channel upon adsorption of a molecule on the sensor surface.[5] The uniqueness of graphene among other solid-state materials is that all carbon atoms are located on the surface, making the graphene surface potentially highly sensitive to any changes of its surrounding environment. Along with the excellent electrical properties of graphene,[13, 14] i.e., extraordinary high mobility,[15, 16, 17] and low intrinsic electrical noise,[18-21] graphene-based electronic biosensors demonstrated greater sensitivity than traditional bioassays.[22] Additionally, graphene (at least ideal graphene) has a crystal lattice free of dangling bonds and is therefore intrinsically chemically inert. This inertness has been a driving force for the first attempts aiming at biointerfacing graphene with specific recognition moieties, via both covalent[23-27, 28] and non-covalent[29-32] approaches, using different biochemical molecules and chemical treatments.

This article aims to provide a comprehensive overview and critical insights on biosensors using the surface of graphene as the sensing element. We evaluate the electronic and the chemical advantages of graphene, i.e., the high carrier mobility, low intrinsic electrical noise and the inert chemical properties, which are at the core of the sensing mechanisms but also crucial in applications where graphene must be interfaced with biological systems. Particularly, we highlight the importance of the chemistry of the graphene basal plane for sensing within the Debye screening length and shed light on the possibilities of sensing beyond the Debye screening.

2. Physics of graphene field-effect transistors (GFETs): the basics for sensing

Graphene nanoelectronics provide a versatile platform for a wide spectrum of biochemical sensing applications.[33] Detection can be realized through various mechanisms, including charge transfer,[14] charge scattering,[35]
capacitive effect,\cite{36} and field effects.\cite{6,7,37} The field effect (i.e., the modulation of the electrical conductivity of a material upon the application of an external electric field, for example, induced by a charged biomolecule) has been widely regarded as the most reliable sensing mechanism. This effect has been harvested to design the first graphene field-effect transistor (GFET),\cite{4} which has inspired considerable experimental and theoretical work relating to the application of GFETs for high performance label-free chemical and biological sensors.\cite{5-12,37}

2.1. Back-gated GFETs.

The word transistor is a combination of two words: transfer and resistor. Usually a transistor is used to switch or amplify an electronic signal, comparable to a tap-valve that controls the supply and flow of water. Fig. 1a depicts a back-gated GFET composed of a source/drain metallic electrode bridged together with a graphene channel. The carrier density, and thus the conductivity of the channel is typically modulated by the electric field by gating a highly conductive silicon substrate located underneath an insulating SiO$_2$ dielectric layer to a range of voltages. As shown in Fig. 1b, a typical measurement consists in applying a constant bias voltage, $V_{sd}$, between the source and the drain of the graphene channel, and monitor the resulting source-drain current $I_{sd}$. A direct consequence of the electronic band structure of graphene\cite{4,14} is that graphene-based FET devices are of metallic nature and cannot be switched off at room temperature. Besides chemical modification, graphene nanoribbon, graphene nanomesh, and graphene nanoring,\cite{38} have also been proved as rational designs of the graphene to open a bandgap, yielding an improved transistor $I_{on}/I_{off}$ ratio. Nevertheless, the transistor $I_{on}/I_{off}$ ratio has no direct relation to the performances of a sensor device, although it is related to graphene digital applications requiring high on state current ($I_{on}$) and ultra-low power consumption at the off state ($I_{off}$) of the transistors. By changing the back gate voltage $V_g$, the electrochemical potential of the charge carriers (i.e., the Fermi energy) can be modulated. As a consequence, the type of charge carriers (which flow in the graphene channel and give the current $I_{sd}$) can continuously be tuned from holes (red curve in the left of Fig. 1b) to electrons (gray curve in the right of Fig. 1b), yielding a so-called 'ambipolar behavior'. At the transition between the electron and hole regime, the current is minimized and this point is also known as the charge neutrality point (CNP).
Fig. 1 Working principle of a graphene field-effect transistor (GFET). (a) Schematic of a back-gated GFET. (b) Typical ambipolar transfer characteristics showing that the type of carriers in graphene can continuously be modulated from holes (on the left, in red) to electrons (on the right, in gray) using the field effect. The charge-neutrality point (CNP) is located at the transition between the electron and hole regime, where the current is minimized. (c) Schematic of a liquid-gated GFET biosensor and its sensing principle (d-f). In the upper panel of (e), a receptor molecule is immobilized on the graphene surface. The plots of $I_{sd}$ versus $V_{ref}$ and $I_{sd}$ versus the time $t$ are shown in the middle and lower panels, respectively. The abbreviation ‘h’ in red refers a measurement carried in the hole regime and ‘e’ for the electron regime in gray. (f) (respectively d) depicts the field effect resulting from the binding of positively (respectively negatively) charged target biomolecule on the receptor (as indicated by the gray arrows in the $I_{sd}(t)$ curves). The binding of a charged biomolecule as indicated by the blue arrows yields a shift in the curves of $I_{sd}$ versus $V_{ref}$.

2.2. Liquid-gated GFETs: operation and sensing principle

A change in the electric field can either be achieved using the above discussed back-gate voltage or be induced by physisorption or chemisorption of the target molecules. When the back-gate is held at a fixed voltage the change in current between the drain and source must thus be due to molecules adsorbed on the graphene surface, as demonstrated in a pioneering study by the Manchester group in 2007 with single molecule detection capability upon NO$_2$ chemosorption.$^{[5]}$
In contrast to the back-gate geometry, in a liquid-gated configuration the gate voltage is applied to the electrolyte via a reference electrode (Fig. 1c). The reference electrode is coupled to the graphene channel through an interfacial capacitance $C$, consisting of a series of two capacitances,[37] namely the quantum capacitance of graphene ($C_Q$),[39] and the double layer capacitance of the electrolyte ($C_{DL}$).[40] The double layer capacitor is a virtual capacitor formed by the separated charges located at the solid side and the solution side of the interface as described by the Poisson-Boltzmann equation.[41] Liquid-gated GFET biosensors belong to the large family of ion-sensitive FETs, the first new concept of which was investigated by Bergveld with Si devices.[42, 43] Although the choice of the channel materials, the reference electrode, the operational mode, and the final encapsulation for liquid handling, vary from case to case, the heart of any ion-sensitive FETs lies on the interface between electrolyte and the solid FET material. In general, GFETs are operated at low electrolyte gate voltage such that any electrochemical processes and exchange ionic currents are negligible, i.e., the interface is considered to be inert and purely capacitive, although this assumption is not always explicitly stated in most of the literature. Experimental artifacts at moderate or relatively high electrolyte gate voltages resulting from such simple assumption are considered mainly of electrochemical nature that will be separately discussed in Section 4.4: Graphene-based electrochemical (GEC) biosensors.

The working principle of a liquid-gated GFET biosensor is illustrated in Fig. 1d-f. In practice, liquid-gated GFETs can be integrated into microfluidic systems:[22] the confinement into the fluidic channel helps in bringing the analyte to the sensor surface.[44] In a typical measurement, receptor molecules are immobilized on the surface for selective recognition of target biomolecules (Fig. 1e, upper panel). The corresponding $I_{sd}$ versus $V_{ref}$ curve of such a liquid-gated GFET is shown in the middle panel (Fig. 1e) with similar characteristics as the one observed for a back-gated GFET (Fig. 1b). The lower panel of Fig. 1e depicts the time dependent current $I_{sd}$ at a fixed reference potential $V_{ref}$ (as indicated by the dashed gray lines). In either the hole regime (as indicated by ‘h’) or in the electron regime (‘e’), when a positively charged target binds (Fig. 1f, upper panel), a depletion of hole carriers (respectively an accumulation of electron carriers) in the graphene occurs due to the field effect. Such doping effect causes a negative shift of the $I_{sd}(V_{ref})$ curve as indicated by the blue arrow in Fig. 1f (middle panel).

In the time-dependent measurement (i.e., the lower panel of Fig. 1f), the binding of a positively charged molecule causes a decrease of the current $I_{sd}$ in the hole regime, and an increase of the current in the electron
regime. Conversely, the binding of a negatively charged molecule (Fig. 1c) induces a positive shift of the \( I_{sd}(V_{ref}) \) curve and an increase in the \( I_{sd} \) in the hole regime. In the electron regime – instead – the same event induces a negative shift of the \( I_{sd}(V_{ref}) \) curve and a decrease of the current \( I_{sd} \). This current modulation in the graphene channel can be expressed as a function of the change in the carrier density \( \Delta n \), which is induced by and is proportional to the total number \( N \) of charged biomolecules adsorbing on the graphene surface:\[45\]

\[
\Delta I_{sd} = \frac{w}{l} V_{sd} e \mu \Delta n \propto N
\]  

(1)

where \( w \) and \( l \) are the width and length of the graphene channel, respectively, \( e \) is the electron charge, and \( \mu \) is the charge carrier mobility. In Eq. 1, it is clear that the sensing response of a transistor sensor should be proportional to the total number of adsorbed biomolecules \( N \). The quantitative monitoring of biomolecules, however, is non-trivial. Challenges lie in characterizing the number of charges each biomolecules carry, in controlling the chemical functionalization, and in identifying the exact sensing reactions at the graphene surface in each different regimes.

We would also like to note here that, in principle, non-charged molecules should have no influences on the field-effect sensing response of GFET sensors, unless they can induce a charge variation (for example, through subtle dipole fluctuation\[46\] or molecular engineering\[47\]). To deduce Eq. 1, we assume that graphene has a constant carrier mobility \( \mu \) upon the adsorption of biomolecules. This assumption is correct in most cases where the adsorbed biomolecules bind to the receptors and interact weakly with the graphene lattice. However, biomolecules that directly bind on a graphene surface form additional scattering centers, resulting in a change of the mobility of charge carriers.\[35\] Additionally, practical sensor designs also take into account the changes in interfacial capacitance upon biomolecules adsorption.\[36\]

2.3. Sensing with graphene of high carrier mobility

The change of the electrical current \( \Delta I_{sd} \) resulting from the minute field-effect induced – for example – by the interaction of a biochemical molecule carrying an electron charge \( e \), defines the sensing response \( S = \Delta I_{sd}/N \).

According to Eq. 1, \( S \) is therefore proportional to the mobility \( \mu \) of graphene. With other parameters equal (especially the electrical noise performance), a higher sensing response \( S \) implies a better sensor performance.

Because the performance of GFET sensors depends on the mobility \( \mu \), the use and integration of high quality graphene into devices is preferential. To achieve high-quality pristine monolayer or few layer graphene sheets, the
most commonly used method is the micromechanical cleavage of graphite with adhesive tape.\textsuperscript{[4]} This so-called ‘scotch tape’ technique involves splitting few layers of graphene from multi-layered graphite, after which the flakes are pressed and ‘dry-deposited’ onto a silicon wafer. Compared to graphene synthesized using other methods, micromechanical cleavage yields graphene with higher mobility and lower intrinsic electrical noise, primarily because fewer structural defects are introduced upon preparation.\textsuperscript{[48]} Generally, for exfoliated graphene on SiO\textsubscript{2}/Si wafers, mobilities on the order of ~3,000-15,000 cm\textsuperscript{2}/Vs are reported,\textsuperscript{[49]} which is more than one order of magnitude higher than those of silicon materials (~100-1,500 cm\textsuperscript{2}/Vs).\textsuperscript{[1, 50]} The mobilities of the first graphene-based gas sensor devices were ~5,000 cm\textsuperscript{2}/Vs.\textsuperscript{[5]} Nowadays, at room temperature, carrier mobility up to 100,000-197,600 cm\textsuperscript{2}/Vs, can be achieved by encapsulating graphene in boron nitride (BN).\textsuperscript{[17, 51, 52]} providing unprecedented possibilities for sensing applications. The fact that this idea has only been realized very recently (with h-BN capped MoS\textsubscript{2})\textsuperscript{[53]} is not a surprise: groups that work on high quality BN coated graphene samples, very often focus on cryogenic measurements of the physics of the 2D electron gases in graphene rather than its biological sensing applications; moreover, the fabrication methods are very delicate (it is not yet trivial to achieve an ideal interface) and the lack of scalability is still an important drawback.\textsuperscript{[17]}

Despite all the impressive achievements in the electrical performances of graphene devices, the reproducibility and homogeneity of sample preparation and the relatively small size (on micrometer scale) represent the bottleneck for using exfoliated graphene for practical applications. Larger sheets of few-layer or monolayer graphene can now be directly synthesized via chemical vapor deposition (CVD) on nickel or copper substrates\textsuperscript{[54, 55]} with mobilities rivalling the ones of exfoliated samples.\textsuperscript{[56]} For samples placed on SiO\textsubscript{2}/Si wafers, mobilities on the order of ~1,000-10,000 cm\textsuperscript{2}/Vs are now routinely observed and regarded as the standard for graphene transistor products for biochemical sensing applications.\textsuperscript{[57]} The electronic performances of CVD graphene\textsuperscript{[58]} can be significantly enhanced by growing single-crystal graphene free of grain boundaries\textsuperscript{[59]} and by using a BN substrate similarly to exfoliated graphene, with which mobility up to ~50,000-350,000 cm\textsuperscript{2}/Vs can be achieved.\textsuperscript{[60, 61]} These mobility numbers are rivaling those of exfoliated samples, making the CVD process ideal for large-area synthesis of high-quality and uniform graphene for sensing applications.

2.4. Electrical noise performances of graphene materials

At low frequencies (∼100 Hz), the ubiquitous 1/f noise, whose power spectral density (PSD) spectrum inversely
depends on the frequency $f$, seriously impedes the sensing performances of GFET. This low-frequency $1/f$ noise is even more pronounced for devices that are scaled down to nanometer dimensions, where the channel current becomes more prone to fluctuations due to, particularly, interface and surface trap states. It is the level of these unwanted fluctuations (along with the sensing response $S$) that determines the ultimate detection limit of GFET biosensors. The $1/f$ noise of graphene monolayers supported on a substrate is comparable to that of bulk semiconductors (including Si). For freestanding or bilayer graphene, however, the $1/f$ noise was found to be one order of magnitude lower through the effective screening of potential fluctuations from external charged impurities (for example, oxide traps or interface states). The fact that graphene possesses both superior mobility and noise performances, gives it a better signal-to-noise ratio (SNR) as advocated from time to time by literature, reporting graphene based biochemical sensors with superior performances compared to their Si based counterpart devices. Fig. 2b compares the noise performances of a GFET device supported by a SiO$_2$/Si substrate and its counterpart after suspending the graphene monolayer by etching the underlying SiO$_2$ substrate (Fig. 2a). The large noise suppression was mainly attributed to the removal of any external trap states in the supported SiO$_2$ substrate since the $1/f$ noise in graphene devices is a surface phenomenon.

Similarly, defects in the graphene are another source of noise. For example, the permanent oxygen-based defects contained in graphene oxide (GO) or reduced graphene oxide (rGO) – introduced by over-oxidation (for GO) or incomplete removal of oxygen groups (for rGO) – lead to inferior electrical quality (i.e., degradation in the mobility and noise performance) compared to scotch-tape or CVD graphene. Interestingly, environmental exposure and ageing of graphene devices also increase the level of noise, suggesting that a proper capping layer or surface functionalization may circumvent an increase of noise. Indeed, by encapsulating a single layer graphene between two layers of hexagonal boron nitride (h-BN, as shown in Fig. 2c), the noise spectral density normalized to the channel area (blue dots, Fig. 2d) can be suppressed up to one order of magnitude lower compared to non-encapsulated devices on Si/SiO$_2$ (red dots, Fig. 2d). In the case of silicon FET, the functionalization of the sensor channel (in this case a silicon nanowire buried in a SiO$_2$ dielectric) with 3-aminopropyl-triethoxysilane (APTES) yields better noise performances (up to 60 times), presumably due to the passivation of the oxide traps and interface states at the sensor surface. On the contrary, for carbon nanotubes, a two-level random telegraphic noise (RTN) was reported and ascribed to a single probe molecule (more precisely, the binding and unbinding of
charged target biomolecules at its active sites), which was covalently bound to a defect in the carbon nanotube sidewall.\textsuperscript{[72]} A suppression of the RTN was observed in high ionic strength buffer solutions (ionic screening) and for high gate potentials (when the target biomolecules are repelled from the nanotube). The influence of surface functionalization on the noise performances of liquid-gated GFETs has not yet been systematically studied. As we described in the previous Section 2.3, with other parameters equal (especially the electrical noise performance), a higher mobility implies a better sensor performance when considering the adsorption of charged biomolecules. We would like to note here that a higher mobility also complies with graphene bearing less defects and impurities, which is in favor of an improved noise performance (although there is still not enough experimental evidences or theories that could directly and unambiguously link the high mobility of GFETs to their noise performances).

Fig. 2 (a) Schematic representation of the experimental setup where a single-layer graphene is supported in solution by Cr/Au contacts to bridge a trench in the oxide. The inset shows an SEM image of a suspended graphene device. Scale bar is 0.5 μm. (b) Comparison of graphene’s noise power spectra in the linear operating modes with holes as carriers before (black) and after suspension of the graphene layer (red). The red/black spikes are due to 50 Hz noise coupled from the power lines. (c) Schematics of BN-graphene-BN FET. (d) Noise amplitude as a function of the gate voltage for both BN-graphene-BN FET (in blue) and conventional non-encapsulated GFET on Si/SiO\textsubscript{2} wafer (in red). (e) The biomolecules carry zero net charge due to the Debye screening effect of ions in electrolyte. (f) Relative changes in resistance ($\Delta R/R$) of a carbon nanotube transistor versus buffer concentration. Increasing the buffer concentration will reduce the Debye length ($\lambda_D$) so that most of the DNA’s negative charge will be screened by counter ions in the electrolyte, resulting in a decreased sensing response ($\Delta R/R$). Inset: schematic representation of a DNA molecule binds on the sidewall of a carbon nanotube. Reprinted with permission.
2.5. Debye screening

The true potential of graphene sensors in physiological solutions (and electrical sensors in general) is still behind expectations. This is because that GFETs are primarily sensitive to the charges carried by the biomolecules adsorbed on graphene surface, which suffer from the ionic screening due to mobile ions present in the solution, known as Debye screening effect.\[73\] In electrolytes, this screening effect is characterized by the Debye length, which is the measure of how far a charge carrier's net electrostatic effect persists, outside of which charges are effectively screened and only 36.8 % (1/e, e=2.72) of the charges can still be seen by the graphene sensing devices. This screening layer (or diffuse layer) is composed of movable ions attracted to a charged surface via the Coulomb force (Fig. 2e). The Debye screening effect is an intrinsic thermodynamic property of large systems of mobile charges. In the following we will examine the Debye screening dilemma in details and look into recent progresses.

For aqueous solutions at room temperature, the Debye length (in unit of nanometer) is given by:\[74\]
\[ \lambda_D = 0.304 / I^{1/2} \]
where \( I \) is the ionic strength expressed in mol/L (M), and is typically ~0.7 nm in physiological conditions. Given the typical several nanometer size of biomolecules, it is therefore likely only small – or even no net electrostatic effect – can be recorded by the transistor (see Fig. 2c). In Tab. I, we have summarized the sensing responses of several ion-sensitive FETs (including nanowire, nanotube and graphene ion-sensitive FETs) at different salt concentrations and biomolecule-to-sensor distances. Indeed, under physiological conditions of 1×PBS (\( \lambda_D \approx 0.7 \) nm) and near side distance of ~1 nm (for example for biotin receptors anchored on the transistor surface), nanowire ion-sensitive FETs showed no response upon the binding of streptavidin from a 10 nM solution.\[74\] Even at low salt concentrations, the sensing response upon hybridization of complementary DNA molecules (i.e., the normalized resistance change) was found to decrease dramatically from 80 % to 12 % by increasing the buffer concentration from 0.1×PBS to 1×PBS in a manner that follows the Debye length considerations (as given by the black fitting line in Fig. 2f).\[72\] Increasing further the buffer concentration to 10×PBS resulted in a full screening of the biological binding signal even at a relatively high DNA concentration of 1 μM.
Tab. I. Selected summary of Debye screening length limitation

<table>
<thead>
<tr>
<th>Surface modification + Target biomolecules</th>
<th>Distance $^1$</th>
<th>Debye length $\lambda_D$ (buffers $^2$)</th>
<th>Concentration &amp; relative sensitivity ($\Delta R/R$)</th>
<th>Refs (comments)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Biotin + Streptavidin</td>
<td>$\sim 1$ nm</td>
<td>$\sim 7$ nm (0.01×PBS)</td>
<td>$10$ nM $\sim 15$ %</td>
<td>$^{[74]}$ Nanowire</td>
</tr>
<tr>
<td>ssDNA + ssDNA (complementary)</td>
<td>At surface</td>
<td>$\sim 3$ nm (0.05×PBS)</td>
<td>$10$ pM $\sim 15$–40 %</td>
<td>$^{[74]}$ Nanowire</td>
</tr>
<tr>
<td>ssPNA + ssDNA</td>
<td>$2.6$ nm (fully complementary)</td>
<td>$\sim 10$ nm (0.01×SSC)</td>
<td>$1$ nM ($1$ mM) $\sim 30$–51 %</td>
<td>$^{[74]}$ NanoWire</td>
</tr>
<tr>
<td></td>
<td>$7.7$ nm (noncomplementary)</td>
<td>$1$ nM</td>
<td>$\sim 0$%</td>
<td></td>
</tr>
<tr>
<td>APTES$^{III}$ + PSA$^{IV}$</td>
<td>$&lt;0.8$ nm</td>
<td>$\sim 7$ nm (1 mM PB)</td>
<td>$100$ nM $\sim 112$ mV$^*$</td>
<td>$^{[76]}$ NanoWire</td>
</tr>
<tr>
<td>Bare graphene + BSA$^V$ (nonspecific)</td>
<td>At surface</td>
<td>$\sim 2$ nm (10 mM PBS)</td>
<td>$300$ pM $\sim 2$ %</td>
<td>$^{[10]}$ Graphene</td>
</tr>
<tr>
<td>20-mer DNA aptamer + ATP$^VI$</td>
<td>$&lt;2.6$ nm</td>
<td>$\sim 2$–3 nm (5–10 mM PB)</td>
<td>$10$ pM $\sim 1$ %</td>
<td>$^{[77]}$ Graphene</td>
</tr>
<tr>
<td>PSA monoclonal antibody + PSA$^V$</td>
<td>$&lt;15$ nm</td>
<td>$\sim 70$ nm (1 μM PBS)</td>
<td>$1$ nM $\sim 17$ %</td>
<td>$^{[76]}$ Graphene</td>
</tr>
</tbody>
</table>

$^1$ Near side distance of the target biomolecules from the device surface
$^2$ Please refer to the according literature for the exact background ionic strength and pH value of the buffer solutions
$^III$ Prostate specific antigen, prostate cancer biomarker
$^IV$ (3-aminopropyl)-triethoxysilane
$^V$ Bovine serum albumin
$^VI$ Adenosine triphosphate
$^*$ Relative changes not given
N.B.: $T = 293K$ unless stated otherwise.

The Debye screening effect has put a fundamental limit to the possible applications of the graphene ion-sensitive FETs (and ion-sensitive FETs in general) for biosensing applications, although ion-sensitive FETs can, in principle, be sensitive to changes below one single charge.$^{[5,79]}$ There are numerous evidences in the literature that the sensing performances can be improved by circumventing the Debye screening effect, for example by designing short antibodies, by performing ex situ measurement in low ionic strength buffers, and by incorporating porous polymer layers permeable to biomolecules (Tab. I).$^{[74-77,80]}$ At the end of this review, we will discuss in details that recent progresses on operating GFETs at high frequencies suggested that Debye screening can be overcome:$^{[46]}$ 1. without any special design or engineering of the receptor molecules and the sensor environments, and 2. in physiological conditions to facilitate in-situ, real-time biosensing.

3. Meeting the challenges in chemical functionalization of graphene for biochemical sensing

Due to its large aromatic sp$^2$ carbon lattice, free of dangling bonds, graphene is intrinsically chemically inert.$^{[12]}$ The broad sensing potential of graphene can only be unlocked by the introduction of sensitizer (bio)molecules and structures, e.g. various inorganic groups,$^{[23-25,81-90]}$ organic or organometallic molecules,$^{[37,91-93,94-96]}$ DNAs,$^{[97-101]}$
proteins,[102] peptides,[30, 31, 103, 104] nanoparticles,[105, 106, 107] and 2D heterostructure.[51, 52, 61, 108] These molecules are able to respond chemically or physically to their nearby environment, whose responses could then be transduced into an appreciable change in the conductivity of the carbon-based honeycomb scaffold. The introduction of such chemical moieties on the graphene surface or edge is often referred to as graphene functionalization.[109, 110]

Chemical functionalization of graphene is commonly achieved using either covalent[23-27, 28] or non-covalent[29-32] strategies. The resulted graphene materials contain specific recognition moieties for biochemical sensing, but still share, to a large extent, the same carbon honeycomb backbone and the electrical properties, especially the field effect, of graphene. In our review, we generally included all the correspondingly developed electronic biochemical sensors based on graphene and functionalized graphene. The physics of GFETs described in previous Section 2 can serve as the basics for sensing of (functionalized) graphene in general. A selected list of frequently used graphene surface chemistry (and their influences on the electrical properties of graphene) is presented in Tab. II.

Typically, covalent approaches reliably modify the graphene surface with various functional biochemical molecules[26] by reacting with the sp² carbon centers in the aromatic lattice, introducing sp³ centers at the reaction sites. Precautions have to be taken as such chemical modification reduces the flatness, but more importantly, destroys the aromaticity of the graphene lattice and renders the modified material inferior in terms of electrical mobility compared to pristine graphene (and noise performances as well, but not shown in Tab. II). On the contrary, non-covalent approaches provide the opportunity to functionalize graphene without disrupting its intrinsic aromaticity.[32] Instead, an increase in the mobility of functionalized devices compared to pristine devices was observed from time to time, especially for h-BN sandwiched graphene samples (see Tab. II). Thus, non-covalent strategies are very appealing for realizing high-performance sensors.
Tab. II. Selected examples of frequently used graphene surface modifications

<table>
<thead>
<tr>
<th>Surface modification</th>
<th>Functional group</th>
<th>Degree of functionalization</th>
<th>Device performance (mobility)</th>
<th>Ref (comments)</th>
</tr>
</thead>
<tbody>
<tr>
<td></td>
<td></td>
<td>Unmodified</td>
<td>Modified</td>
<td>Pristine (m²/Vs)</td>
</tr>
<tr>
<td>Hydrogenation/ (Graphene)</td>
<td>H</td>
<td>-</td>
<td>-</td>
<td>~14000 (40-160 K)</td>
</tr>
<tr>
<td></td>
<td>H</td>
<td>1/1/ = 0.1&lt;sup&gt;a&lt;/sup&gt;</td>
<td>1/1/ = 1.43&lt;sup&gt;b&lt;/sup&gt;</td>
<td>1100</td>
</tr>
<tr>
<td></td>
<td>H</td>
<td>1/1/ = 2.05&lt;sup&gt;c&lt;/sup&gt;</td>
<td></td>
<td>59</td>
</tr>
<tr>
<td>Fluorination&lt;sup&gt;d&lt;/sup&gt;</td>
<td>F</td>
<td>1/1/ = 0&lt;sup&gt;d&lt;/sup&gt;</td>
<td>1/1/ = 3.6&lt;sup&gt;c&lt;/sup&gt;</td>
<td>-</td>
</tr>
<tr>
<td></td>
<td>F</td>
<td>-</td>
<td>F/C 0.21- 0.25&lt;sup&gt;e&lt;/sup&gt;</td>
<td>-</td>
</tr>
<tr>
<td>Chlorination&lt;sup&gt;e&lt;/sup&gt;</td>
<td>Cl</td>
<td>-</td>
<td>w% Cl = 42.6</td>
<td>2076</td>
</tr>
<tr>
<td></td>
<td>Cl</td>
<td>-</td>
<td>w% Cl = 20.5</td>
<td>5000</td>
</tr>
<tr>
<td>Oxidation&lt;sup&gt;f&lt;/sup&gt; (reduced GD)&lt;sup&gt;g&lt;/sup&gt;</td>
<td>COOH, OH, R-O-R</td>
<td>1/1/ = 0.91&lt;sup&gt;i&lt;/sup&gt; (for GD)</td>
<td>/1/ = 1.15&lt;sup&gt;i&lt;/sup&gt; (hydrati no)</td>
<td>-</td>
</tr>
<tr>
<td></td>
<td>COOH, OH, R-O-R</td>
<td>-</td>
<td>w% O = 5.6 (NaOH)</td>
<td>-</td>
</tr>
<tr>
<td>Graffiti&lt;sup&gt;h&lt;/sup&gt; (diazonium salt)</td>
<td>p-bromophenyl</td>
<td>-</td>
<td>t = 30 min</td>
<td>~1750</td>
</tr>
<tr>
<td></td>
<td>p-bromophenyl</td>
<td>-</td>
<td>t = 60 min</td>
<td>~2400</td>
</tr>
<tr>
<td></td>
<td>p-bromophenyl</td>
<td>-</td>
<td>t = 90 min</td>
<td>~1900</td>
</tr>
<tr>
<td></td>
<td>p-bromophenyl</td>
<td>-</td>
<td>t = 120 min</td>
<td>~950</td>
</tr>
<tr>
<td></td>
<td>p-nitrophenyl</td>
<td>1/1/ = 0&lt;sup&gt;d&lt;/sup&gt;</td>
<td>1/1/ = 1.5&lt;sup&gt;c&lt;/sup&gt;</td>
<td>~2000 (on SiO₂)</td>
</tr>
<tr>
<td>Organometallic molecule&lt;sup&gt;i&lt;/sup&gt; (π-π or hydrophobic)</td>
<td>TPA (Aromatic molecules)</td>
<td>-</td>
<td>-</td>
<td>-</td>
</tr>
<tr>
<td></td>
<td>Pe-porphyrin</td>
<td>-</td>
<td>-</td>
<td>~8000 (4-2K)</td>
</tr>
<tr>
<td></td>
<td>Vanadyl phthalocyanine</td>
<td>-</td>
<td>p&lt;sup&gt;∞&lt;/sup&gt; = 5 × 10&lt;sup&gt;15&lt;/sup&gt; cm&lt;sup&gt;-2&lt;/sup&gt;</td>
<td>2000-3000</td>
</tr>
<tr>
<td>DNA and protein&lt;sup&gt;j&lt;/sup&gt; (π-π or hydrophobic)</td>
<td>Adenine (A)</td>
<td>-</td>
<td>0.8 ML&lt;sup&gt;e&lt;/sup&gt;</td>
<td>~1620</td>
</tr>
<tr>
<td></td>
<td>Thymine (T)</td>
<td>-</td>
<td>0.85 ML&lt;sup&gt;e&lt;/sup&gt;</td>
<td>~1540</td>
</tr>
<tr>
<td></td>
<td>Cytosine (C)</td>
<td>-</td>
<td>1.1 ML&lt;sup&gt;e&lt;/sup&gt;</td>
<td>~1340</td>
</tr>
<tr>
<td></td>
<td>Guanine (G)</td>
<td>-</td>
<td>1 ML&lt;sup&gt;e&lt;/sup&gt;</td>
<td>~1640</td>
</tr>
<tr>
<td></td>
<td>ssDNA I (12-mer)</td>
<td>-</td>
<td>-</td>
<td>305.2</td>
</tr>
<tr>
<td></td>
<td>ssDNA II (12-mer)</td>
<td>-</td>
<td>-</td>
<td>607.1</td>
</tr>
<tr>
<td></td>
<td>ssDNA (21-24-mer)</td>
<td>-</td>
<td>-</td>
<td>2600</td>
</tr>
<tr>
<td>Polyelectrolyte multilayer&lt;sup&gt;k&lt;/sup&gt; (Electrostatic)</td>
<td>polyelectrolyte (PAH+ and PS9-)</td>
<td>1/1/ = 0.1&lt;sup&gt;a&lt;/sup&gt;</td>
<td>-</td>
<td>~1556</td>
</tr>
<tr>
<td>Nanoparticle&lt;sup;l&lt;/sup&gt; (van der Waals)</td>
<td>Pd nanoparticles</td>
<td>1/1/ = 0.1&lt;sup&gt;a&lt;/sup&gt;</td>
<td>1/1/ = 0.1&lt;sup&gt;a&lt;/sup&gt;</td>
<td>2405</td>
</tr>
<tr>
<td></td>
<td>Ag nanoparticles</td>
<td>-</td>
<td>p&lt;sup&gt;∞&lt;/sup&gt; = 6.2 × 10&lt;sup&gt;15&lt;/sup&gt; cm&lt;sup&gt;-2&lt;/sup&gt;</td>
<td>~810</td>
</tr>
<tr>
<td></td>
<td>Ag nanoparticles</td>
<td>-</td>
<td>p&lt;sup&gt;∞&lt;/sup&gt; = 9.4 × 10&lt;sup&gt;15&lt;/sup&gt; cm&lt;sup&gt;-2&lt;/sup&gt;</td>
<td>~600</td>
</tr>
<tr>
<td>2D heterostructure&lt;sup&gt;m&lt;/sup&gt; (van der Waals)</td>
<td>h-BN</td>
<td>-</td>
<td>Sandwiched</td>
<td>~15000 (on SiO₂)</td>
</tr>
<tr>
<td></td>
<td>h-BN</td>
<td>-</td>
<td>Sandwiched</td>
<td>197600</td>
</tr>
<tr>
<td></td>
<td>h-BN</td>
<td>-</td>
<td>Sandwiched</td>
<td>~350000</td>
</tr>
</tbody>
</table>

<sup>a</sup> covalent functionalization
<sup>b</sup> non-covalent functionalization
<sup>c</sup> GO is used as the starting material for rGO. GO is an insulator; hence no pristine device mobility is provided.
<sup>d</sup> 1/1/ as a measure of sp<sup>3</sup>/sp<sup>2</sup> in the graphene lattice. Increased ratio correlates with increased sp<sup>3</sup> over sp<sup>2</sup> (more defects).
<sup>e</sup> F/C as a measure of degree of fluorination: ratio of fluorine over carbon atoms in the material.
<sup>f</sup> t = reaction time for the functionalization of graphene with diazonium salt.
<sup>g</sup> ML = monolayer of the introduced functional moiety on graphene.
<sup>h</sup> e<sub>imp</sub> is the amount of functional groups or nanoparticles at the surface of graphene per square centimeter.
<sup>i</sup> N.B.: single layer graphene or rGO unless stated otherwise; T = 293K unless stated otherwise.

3.1. Covalent functionalizations

Covalent chemical modification of graphene allows engineering the properties of graphene to a large extent, particularly with the scope of band gap engineering, surface modification, and biointerfacing. [109] Introducing atomic hydrogen or fluorine into the honeycomb scaffold, reveals the possibility to continuously transform this highly conductive zero-band gap semimetal into an insulator known as graphene [23] (Fig. 3a) or 2D Teflon, [24, 81] as
initially proposed by the Manchester group. Regarding sensing applications, calculations showed that (partially) hydrogenated graphene has a high affinity for NO$_2$;\textsuperscript{[111]} while graphane doped with Li adatoms was predicted to be sensitive to H$_2$S and NH$_3$;\textsuperscript{[112]} Moreover, the reduced carrier mobility of highly hydrogenated graphene is still sufficient for sensor applications;\textsuperscript{[113]} Fluorographene, on the other hand, was applied for the detection of ammonia,\textsuperscript{[114]} ascorbic acid, and uric acid.\textsuperscript{[115]} The fluorine-enriched material could also be further functionalized with thiol groups for genosensing;\textsuperscript{[116]} Underlying mechanisms and selectivity of the sensor are still under debate.

Separately, graphene sheets are now routinely covalently modified with oxygen functional groups (e.g. carboxyl, hydroxyl and epoxy moieties, see also Fig. 3b) by using oxidative reactions, forming graphene oxide (GO), a material known since the early 1960s.\textsuperscript{[117]} The synthetic process consists in dispersing graphite into stable single layer GO and is suitable for large scale production of dispersible single layer graphene using a thermal or chemical reduction step. The resulting material is often referred to as reduced GO, or rGO;\textsuperscript{[118]} Remarkably, when used as an active sensing electrode, GO and rGO usually show improved sensing responses, presumably due to the large concentration of defects compared to near defect-free single layer graphene obtained via mechanical exfoliation of graphite.\textsuperscript{[25, 119]} One of the first works on rGO as an active material for high-performance molecular sensing describes a conductance change of the rGO networks upon exposure to trace levels of vapor (including three main classes of chemical-warfare agents and an explosive at parts-per-billion concentrations).\textsuperscript{[25]} It was shown that the optimal defect density should balance the gains in the sensor response against the rapid degradation in low frequency 1/$f$ noise due to the increased density of defects.\textsuperscript{[25]} The difficulties in controlling the density of the defect as well as the lack of knowledge on the nature of the defect, however, represents significant limitations for utilizing GO or rGO for sensing applications. Reactive oxygen-rich groups, inherently present on rGO, can be exploited to synthetically conjugate the material with various chemical or biological groups.\textsuperscript{[26]} A viable synthetic strategy is depicted in Fig. 3b: a GO-polyethylene glycol dispersion (i.e., PEGylated GO) was prepared; the hydrophilic six-armed PEG-NH$_2$ could then be labelled by conjugating an antibody (for potential antibody-antigen detection).\textsuperscript{[26]}

Hydrogenated graphene, fluorinated graphene (or halogenated graphene\textsuperscript{[120]} in general), and GO (or rGO) are the few examples of materials that resulted from covalent modification of the graphene scaffold. Instead of providing an extensive list of the methods available to induce such modifications, we will continue with discussing
a grafting strategy, frequently applied to covalently attach chemical moieties to graphene surface (or edges) via free-radical reactions.[27, 28, 109, 121-125] Graphene grafting uses alkyl or aryl diazonium salts as grafting agents, where the diazonium salt precursor is first chemically or electrochemically reduced (liberating nitrogen gas), to form a reactive alkyl or aryl radical that reacts with the aromatic system of the graphene sheet (the conductive channel of the transistor device fabricated on a 200 nm SiO₂/highly doped Si substrate as shown in Fig. 3c).[126]

The disruption of the aromatic system by transformation of carbon atoms from sp² to sp³ hybridization results in a remarkable decrease in graphene conductivity, which can be controlled by reaction time (see also Tab. II). The reaction efficiency depends on several parameters: the number of graphene layers,[122] the electrostatic environment,[123] and the defect density on the graphene surface.[124] A previous study exploited the graphene reactivity, induced by electrostatic charge doping on different substrates using reactivity imprint lithography (RIL).[123] The RIL technique made use of a polydimethylsiloxane (PDMS) stamp to pattern octadecyltrichlorosilane (OTS) lines on a SiO₂/Si substrate (Fig. 3d). During the electrografting of graphene with 4-nitrobenzene diazonium tetrafluoroborate (4-NBD),[28] bare SiO₂-supported graphene showed a stronger reactivity with the diazonium salt than graphene resting on OTS-protected SiO₂ (Fig. 3e). OTS increases the distance between the graphene sheet and the charged impurities in the SiO₂ substrate, rendering the portion of graphene resting on it less reactive to the 4-NBD.[123] Similarly, in case of GO (or rGO), grafting chemistries are best represented by localized reactivity of the carboxyl, carbonyl, and other oxygen-containing groups by substitution reactions.[124]
Fig. 3 Surface chemical functionalizations of graphene materials. (a) Graphene layer (in green) is attacked by cold plasma hydrogen atoms to produce graphane. (b) Bioconjugation of PEGylated GO with antibody. (c) Schematic of the chemical functionalization of a GFET devices with 4-nitrobenzene diazonium tetrafluoroborate (4-NBD). (d) AFM image of octadecyltrichlorosilane (OTS) lines patterned on SiO\textsubscript{2} surface. (e) Raman mapping of I\textsubscript{D}/I\textsubscript{G} for graphene after 4-NBD reactions: 10mM 4-NBD in aqueous solution with 0.5 wt% sodium dodecyl sulfate (SDS) at 35°C for 1.5 h. (f) STM image of a self-assembled monolayer of an aromatic molecule (perylene-3,4,9,10-tetracarboxylic-3,4,9,10-dianhydride, PTCDA) (gas-phase deposition) on a graphene surface (scale bar is 3 nm). Upper panel: molecular structure of PTCDA. (g) Left panel: AFM of highly oriented pyrolitic graphite (HOPG) incubated for 5 min with a solution of 3 M KCl and 8 M urea and rinsed with ultrapure water (scale bar is 200 nm). Right panel: HOPG incubated for 5 min with single-stranded M13 DNA (10 ng μl\textsuperscript{-1}) in the same buffer (scale bar is 200 nm). (h) AFM topographic image of graphene before (left panel) and after (right panel) incubation with the peptide. Reprinted with permission.
3.2. Non-covalent functionalizations

As mentioned in the previous section, non-covalent functionalization has the major advantage of fully preserving the graphene lattice (i.e., the aromaticity), and thus the electrical performances (see Tab. II). In addition, non-covalent bond can also be quite strong. For example, the π-π interactions of graphene-benzene and naphthalene result in a considerable binding energy of almost 0.1 eV per carbon atom; consistently, the binding energy of graphene-TTP (tetraphenylporphyrin) was calculated to be 3.2 eV, i.e., ~90 % of a typical C-C covalent binding energy (~3.6 eV). [127] Given the aforementioned advantages, it is a common approach to anchor a biomolecule onto the graphene surface using an aromatic linker group via non-covalent bonds with excellent sensing performance in aqueous solutions. [109] Still, we would like to note here that non-covalent functionalizations are expected to be less compatible with long term usage, at least if compared to stronger covalent functionalizations (although the covalent modifications of graphene inevitably lead to a severe degradation in the electrical properties). Nevertheless, non-covalent functionalizations could also be an asset if the sensor surface has to be regenerated, for example, for recycling the sensor devices.

In general, non-covalent graphene functionalization approaches can be classified based on their corresponding intermolecular interactions, including π-π or hydrophobic stacking, electrostatic interaction, and van der Waals interaction as also shown in Tab. I. [109] The self-assembly process of these molecules on the surface of graphene could be highly controlled and accurately characterized in favor of an actual sensor design. [109, 110] For example, Fig. 3f shows a scanning tunneling microscopy (STM) image of well-ordered aromatic perylene-3,4,9,10-tetracarboxylic-3,4,9,10-dianhydride (PTCDA) molecules on graphene (as indicated by the a and b vectors), where π-π interaction are the driving force of the self-assembly. [92] The perylene-based monolayer is stable and robust even when exposed to ambient conditions. π-π or hydrophobic interactions between aromatic surface and nucleic acid moieties can also facilitate the decoration of graphene surface with single-stranded DNA (ssDNA) as shown in Fig. 3g (right panel, highly oriented pyrolytic graphite (HOPG) was applied in this case). [128] This strong non-specific ssDNA adsorption can be avoided by first self-assembling a monolayer of pyrene ethylene glycol, thus rendering the surface of graphene hydrophilic and preventing ssDNA adsorption via hydrophobic interactions (left panel, Fig. 3g). Besides DNA, proteins [102] or peptides [30, 31] containing aromatic moieties could also self-assemble on a graphene scaffold. As illustrated in Fig. 3h, the incubation of graphene with the peptides resulted in the
formation of an uniform mesh-like layer whilst silicon oxide surface was unaffected. This indicates that the adsorption occurred specifically on graphene.[31]

Electrostatic interaction is another driving force of the non-covalent assembly. For instance, voltage-biased graphene can act as an electrophoretic electrode for immobilization of charged biomolecules. The subsequent detection of complementary analysts can be achieved by using the same graphene transistor devices.[22, 96, 129]

As suggested by Geim and co-workers,[108] weak van der Waals-like interaction between layers could be exploited to sandwich (a process called ‘encapsulation’) graphene with other 2D layers of, e.g. MoS₂, mica, or hexagonal boron nitride (h-BN). This innovative technique allows the formation of unprecedented multilayer heterostructures that may be used in devices with adjustable and astonishing electronic properties. For example, by encapsulating graphene in a h-BN stacking layer, researchers managed to obtain very high electric performances GFETs, including an exceptionally high carrier mobility of 140,000 cm²/Vs at room temperature, which is close to the theoretical limit as imposed by acoustic phonon scattering. This extremely high mobility could be ascribed to very clean interfaces above and below graphene and effective screening of all the defects.[17] Very recently, even higher mobilities, up to a staggering 197,600 cm²/Vs[52] and 350,000 cm²/Vs[61], have been observed for hBN-sandwiched graphene samples. One could also explore various 2D crystals as active sensing elements, MoS₂ or h-BN capped MoS₂,[53, 130] for instance. Please note that even in a stack such as encapsulated graphene, the encapsulating layers can be functionalized in the quest of sensing (with the requirement that the encapsulating layer is sufficiently thin).

As previously discussed, chemical functionalization is essential for unlocking the sensing potential of graphene surface, but important is also to realize that chemical functionalization also plays a critical role in passivating the surface of graphene. Surface passivation against unwanted non-specific binding (pyrene ethylene glycol to prevent any hydrophobic interactions,[128] for example) is crucial to achieve very low detection limits in the presence of high ionic background levels and to avoid false positives when complex biological samples are assayed.[131]

Importantly, the transfer of large and clean (and crack- and fold-free) graphene sheets is still a critical challenge. Long chain polymers including poly(methyl methacrylate) (PMMA) – conventionally used for transferring two-dimensional materials – irreversibly adsorb on the graphene surface, yielding a range of contaminations with unwanted chemical functions.[132] It is therefore a necessity to take into account the influences of these possible
polymer residues as they impede the functionalization of the graphene surface (which is actually not always discussed, nor clarified in the literature). There is therefore also a large demand for decent polymer-free transfer methods.\textsuperscript{[133]}

Fig. 4 Non covalent functionalizations of graphene with lipids. (a) Stable superstructure of graphene sheet sandwiched within the hydrophobic core of a phospholipid bilayer membrane, (b) AFM images (scale bar is 5 \(\mu\text{m}\)) and the respective height profiles of phospholipid patches on graphene and on silicon oxide, respectively. Graphene induces a merged and uniform lipid patch compared to silicon oxide in the same conditions. (c) Schematic representation of GO sheets interacting with lipid forming stacked and multilayer structures on SiO\(_2\) substrate (by vesicle fusion assembly). Reprinted with permission.

3.3. Graphene lipid superstructures: towards graphene bioelectronics

Graphene bioelectronics represents a highly interdisciplinary field that combines material science with biology and electronics at the interface. The rapid expansion in this field offers the great potential to construct innovative biological cellular sensor devices to overcome existing challenges in bioelectronics and therefore opens up new opportunities in fundamental biology and healthcare.\textsuperscript{[68, 134]} These challenges include the shrinking of the electronic dimensions to micro- or even nanoscale and large-scale integration for high-resolution sampling,\textsuperscript{[135]} but
particularly, a complex but well-defined biocompatible interface between graphene surface and cell is at the core of graphene bioelectronics.

Lipids, as major constituents of the cell membrane, provide a physical barrier between the interior and the exterior of a cell. Along with their associated proteins, lipids are responsible for the key functions of a cell such as the highly controlled selectivity of passage of molecules and ions.\textsuperscript{[136]} Despite the hitherto limited knowledge on lipid-graphene interaction, these basic understandings are actually of vital importance as the starting point of graphene biointerfacing. Molecular dynamics simulations of the interaction between pristine graphene and lipid bilayers revealed a well-defined graphene-sandwiched superstructure most presumably achieved by hydrophobic interactions (Fig. 4a).\textsuperscript{[137]} Precise patterning of phospholipid molecules directly on exfoliated graphene (the left panel of Fig. 4b) can also be achieved by using dip-pen nanolithography.\textsuperscript{[138]} The graphene surface favors a merged and uniformed lipid layer in comparison to the lipid patches patterned on silicon oxide in the same conditions, as the lipids have tendency to slip and spread on the graphene surface (the right panel of Fig. 4b).

Lipid interaction with GO\textsuperscript{[139]} can be harvested to control the assembly of GO sheets into large superstructures as well as to unravel the potential toxicity of graphene derivatives to cells.\textsuperscript{[140]} Previous studies in a Langmuir-Blodgett trough revealed that the negatively charged GO sheets dispersed in water interact with the positively charged lipids head groups present at the air/water interface mainly with two configurations: i) GO sheets positioned vertically to the interface\textsuperscript{[141]} or ii) GO sheets parallel to the interface.\textsuperscript{[142]} To understand how lipids interact with GO on solid substrates, GO has been incubated in the presence of various lipid compositions.\textsuperscript{[143, 144]} Fig. 4c shows a lipid membrane that is first formed on a SiO\textsubscript{2} substrate by vesicle fusion assembly. Second, the negatively charged GO specifically adsorbs on the positively charged lipids, and induces rupture of further adsorbed liposomes, resulting in well-organized lipid-GO multilayered structures.\textsuperscript{[143]}

Advantageously, unlike the conventional solid electronics with rigid surfaces, graphene electronics are well-known for the fabrication of flexible and transparent electrodes.\textsuperscript{[145]} Therefore graphene provides a flexible and conducting substrate that interfaces well with the soft, 3D biological systems.\textsuperscript{[146-148]} For example, the mechanical flexibility and electrical functions of graphene membrane can be used to achieve a strongly coupled electromechanical biointerface by coating yeast cells with an ultrathin layer of rGO (see also Fig. 7f).\textsuperscript{[147]} Nevertheless, most researches on graphene biointerfaces still use graphene on rigid solid substrates at an
intermediate stage mainly focusing on understanding the complicated sensing mechanisms (as the reconfiguration of the fluidic-like lipid layer has to be considered).

For example, a gram-negative bacteria biomimetic membrane was deposited on CVD GFETs (fabricated on a SiO$_2$/Si substrate) for detecting magainin 2, an antimicrobial agent. The presence of magainin 2 disrupts and thins the lipid membrane from a thickness of ~5 nm to ~3 nm. This change in membrane thickness and integrity lead to a significant change in the liquid gate coupling, and thus to a noticeable field effect which could be measured by the GFETs. The self-assembly processes of charged lipid bilayers can also induce a sensing signal in the GFET due to surface charge aggregation. Such GFETs interfaced with biomimetic membrane can even provide enough sensitivity to investigate individual ion channel activity during the insertion of a pore-forming membrane protein. Graphene bioelectronics for cellular sensors will be further discussed in the next Section 4.3.

4. Current trends & efforts in biochemical sensing at the surface of GFETs

There has been a vast interest of industry, society, and scientific community in applying graphene materials for biochemical sensing applications, for portable point-of-care devices for remote diagnostics, for environmental monitoring, and even for DNA sequencing technologies, etc. The outcomes of researches in this area, however, did not reached the marked yet, although ultimate single molecule sensitivity has been demonstrated and prototype biosensor chips in various forms have also been developed. In the following sections, we will critically review the current trends in the development of GFET-based gas and ion sensors, protein and DNA sensors, and cellular sensors in revisiting the ambiguous cases and in meeting the social/scientific needs. A brief introduction to the graphene electrochemical sensors will also be given as their operation and sensing mechanism can be regarded to be complementary to GFET sensing technologies. Before discussing the separated cases, we summarized the sensing performances (and the electrical properties) of GFETs in Tab. III for a selected lists of frequently reported analytes.
As we pointed out in the previous Sections 2.2 and 2.3, it is preferential to use high mobility graphene for sensing applications as: 1. a higher mobility implies a larger sensing response; 2. a higher mobility complies with less defects and surface contaminations, which is in favor of an improved noise performance. Such trend is evidenced, for example, in case of gas sensors. Tab. III showed that for gas detection of both NO₂ and NH₃, exfoliated graphene with high mobility (~5000 cm²/Vs) generally demonstrated a much better detection limit ~1 ppm compared to ~1 – 550 ppm of CVD or rGO with lower mobilities. We may also relate the decrease in the detection limit of DNA molecules – from ~0.001 – 0.01 nM (CVD graphene) to ~48 nM (rGO), and to ~0.175 mM (GO) – to the degradation in the electrical properties of (functionalized) graphene. In our listed cases of DNA

<table>
<thead>
<tr>
<th>Analyte</th>
<th>Graphene device mobility (cm²/Vs)</th>
<th>Detection limit</th>
<th>Corresponding sensing response [ΔI/I<em>100%] or [ΔR/R</em>100%]</th>
<th>Refs (comments)</th>
</tr>
</thead>
<tbody>
<tr>
<td>Gas NO₂</td>
<td>~100</td>
<td>1 ppm</td>
<td>0.99 %</td>
<td>[155] rGO</td>
</tr>
<tr>
<td></td>
<td>~5000</td>
<td>1 ppm</td>
<td>~4 % ([noise level: ~0.1 %])</td>
<td>[157] Exfoliation</td>
</tr>
<tr>
<td></td>
<td>-</td>
<td>20 ppm</td>
<td>24 %</td>
<td></td>
</tr>
<tr>
<td>NH₃</td>
<td>-</td>
<td>200 ppm</td>
<td>16.2 %</td>
<td></td>
</tr>
<tr>
<td></td>
<td>~10</td>
<td>1 ppm</td>
<td>~4 % ([noise level: ~0.1 %])</td>
<td></td>
</tr>
<tr>
<td></td>
<td>~5,000</td>
<td>1 ppm</td>
<td>10.2 %</td>
<td></td>
</tr>
<tr>
<td></td>
<td>5,500</td>
<td>10 ppm</td>
<td>~1.5 %</td>
<td>[158] Exfoliation, annealed</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>10 ppm (noise level: ~0.1 %)</td>
<td></td>
</tr>
<tr>
<td>Ion H⁺</td>
<td>-</td>
<td>0.67pH</td>
<td>27.8 %</td>
<td>[155] rGO</td>
</tr>
<tr>
<td></td>
<td>-</td>
<td>0.34pH</td>
<td>18 %</td>
<td></td>
</tr>
<tr>
<td></td>
<td>3060</td>
<td>-</td>
<td>~4 % ([noise level: ~0.1 %])</td>
<td></td>
</tr>
<tr>
<td>K⁺</td>
<td>~300</td>
<td>100 μM</td>
<td>40 mV/decade</td>
<td>[159] CVD</td>
</tr>
<tr>
<td></td>
<td>-</td>
<td>1 μM</td>
<td>40 mV/decade</td>
<td></td>
</tr>
<tr>
<td></td>
<td>-</td>
<td>1 nM</td>
<td>10 mV/decade</td>
<td></td>
</tr>
<tr>
<td>Na⁺</td>
<td>-</td>
<td>0.34 μM</td>
<td>40 mV/decade</td>
<td>[160] CVD</td>
</tr>
<tr>
<td></td>
<td>-</td>
<td>1 μM</td>
<td>10 mV/decade</td>
<td></td>
</tr>
<tr>
<td></td>
<td>-</td>
<td>1 nM</td>
<td>10 mV/decade</td>
<td></td>
</tr>
<tr>
<td>Cd⁺</td>
<td>-</td>
<td>1 μM</td>
<td>~1 % ([SNR: 15-20])</td>
<td>[156] rGO</td>
</tr>
<tr>
<td></td>
<td>-</td>
<td>1 nM</td>
<td>~2 % ([SNR: 25-30])</td>
<td></td>
</tr>
<tr>
<td></td>
<td>~4000</td>
<td>10 ppm</td>
<td>(back gate voltage shift: ~6.2 V)</td>
<td></td>
</tr>
<tr>
<td>Hg²⁺</td>
<td>-</td>
<td>37.5 ng/L</td>
<td>~2 % ([SNR: 25-30])</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>~4000 (back gate voltage shift: ~5mV)</td>
<td>[167] Exfoliation</td>
</tr>
<tr>
<td>DNA ssDNA</td>
<td>0.068</td>
<td>0.175 mM</td>
<td>71 %</td>
<td>[169] GO</td>
</tr>
<tr>
<td></td>
<td>ssDNA (23-mer)</td>
<td>-</td>
<td>48 nM ([2.4m A C calc. @ SNR=3])</td>
<td>[169] rGO</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>0.01 μM ([2.4m A C calc. @ SNR=3])</td>
<td>[169] GO</td>
</tr>
<tr>
<td></td>
<td>~150-700</td>
<td>0.001 μM</td>
<td>~20 % ([SNR: 10-12])</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>~12 % ([SNR: 20])</td>
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<td></td>
<td></td>
<td>0.01 μM</td>
<td>~12 % ([SNR: 20])</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>0.01 μM ([2.4m A C calc. @ SNR=3])</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>0.01 μM</td>
<td>0 % ([SNR: 20])</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>0.01 μM ([2.4m A C calc. @ SNR=3])</td>
<td></td>
</tr>
<tr>
<td>Protein</td>
<td>Protective antigen (Anthrax toxin)</td>
<td>~1250-1750</td>
<td>300 pM ([2.4m A C calc. @ SNR=3])</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>290 pM</td>
<td>~0.3 %</td>
<td>[171] Exfoliation</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>~0.3 %</td>
<td></td>
</tr>
<tr>
<td>Glucose</td>
<td>Glucose</td>
<td>~2298</td>
<td>1.25 μM ([2.4m A C calc. @ SNR=3])</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td>~25 % ([2.4m A C calc. @ SNR=3])</td>
<td>[172] CVD</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>~1.1 % ([2.4m A C calc. @ SNR=3])</td>
<td>[172] CVD</td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>~0.5 μM ([2.4m A C calc. @ SNR=3])</td>
<td>[172] CVD</td>
</tr>
<tr>
<td>Cell</td>
<td>Embryonic chicken cardiomysocyte</td>
<td>~0.5 μM</td>
<td>~0.5 %</td>
<td></td>
</tr>
<tr>
<td></td>
<td>cell</td>
<td>3000</td>
<td>~0.5 %</td>
<td></td>
</tr>
<tr>
<td></td>
<td></td>
<td></td>
<td>~0.175 mM ([2.4m A C calc. @ SNR=3])</td>
<td></td>
</tr>
</tbody>
</table>

*a mV/decade: liquid gate voltage shift in the Dirac point of a GFET per decade (ion concentration).

b in combination with Si-nanowire device.
detection, we made the comparisons as all the sensing reactions were based on short chain DNA hybridization, and thus sharing comparable (at least to a certain extent) bonding constants. We noted here that, it might not always be fair to make such comparisons, precautions have to be taken as surface condition (functionalization) of graphene as well as the device geometry might be different from sample to sample (and is not always reported in the literature). For example, Tab. III showed that annealing exfoliated graphene exhibited a comparable carrier mobility to as-fabricated exfoliated graphene (from ~5000 cm²/Vs to ~5500 cm²/Vs), but also a strikingly decreased sensitivity to NH₃ gas (from ~1 ppm to ~1000 ppm) due to mainly the different in their surface conditions (see the following section for detailed discussions).

4.1. GFET gas and ion sensors

The very first chemical sensors fabricated using pristine mechanically exfoliated graphene flakes (Fig. 5a) have shown very high sensitivity, down even to single molecule detection for the chemisorbed gaseous NO₂ (and a detection limit higher than 1 ppm for NH₃ as shown in Fig. 5b, at room temperature). [5] The unprecedented high sensitivity was explained as a consequence of the extraordinary low intrinsic noise as well as the largest response of the Hall geometry around the CNP. But this high chemical sensitivity of graphene towards physisorbed gaseous NH₃ is a surprise if considering the fact that graphene is intrinsically chemically inert. [12] Indeed, in more recent studies, inert electrical responses (i.e., no response) for gaseous NH₃ were observed by annealing the exfoliated graphene at high temperature (400 °C) in Ar/H₂ atmosphere to remove possible polymer contaminations and produce atomically clean graphene sheets. [178] This inert sensing behavior of the cleaned graphene sensors is robust even upon the exposure to NH₃ vapor at a concentration of 1000 ppm (Fig. 5c) [11] and to dimethylmethylphosphonate (DMMP) vapor at a concentration of 100 ppm (Fig. 5d). [29] It is now widely accepted that clean graphene should be inert to the presence of most of the gas molecules, although it is possible to amplify the more subtle dipole moment of a charge neutral gas molecule by switching it and mixing the modulated dipole signal in a high frequency setup for detection. [179] The previous observed sensitive responses of pristine graphene to gas molecules could be, therefore, ascribed to defective sensitivities, due to possible defects or polymer contaminations introduced during device fabrication. The edge of graphene, also plays a crucial role in the determination of its physical, electronic and chemical properties and thus in the sensing properties. As an example, holey rGO could be fabricated by using enzymatic oxidation followed by reduction with hydrazine. [180] Such
defective graphene – with abundant edge defects – exhibited a large and selective electronic response toward the
detection of hydrogen, particularly when decorated with Pt nanoparticles.\cite{180} In principle, the substrate surface
conditions are also suspected to influence the edge of graphene, and hence the sensing properties of the GFET
devices especially at nanoscale.\cite{181}

GFET based pH sensors measure the protonation and deprotonation at the (functionalized) graphene surface.
They hold great potentials especially in food industry and medical applications for glass-free pH measurement
requiring the highest level performance, small size, and/or flexibility.\cite{182} In earlier reports, GFET based pH
sensors exhibited large variation in their pH sensitivities, ranging from a low value of 12 mV/pH to a value of 99
mV/pH.\cite{7-10, 21} The latter value is even larger than the thermodynamically allowed maximal shift of 60 mV/pH
(the so-called Nernst value) at room temperature.\cite{8} It became clear later on that the large range of pH-induced gate
shifts observed in the previous literature could be ascribed to defects as well as surface contaminations reflecting
the quality of as-fabricated graphene.\cite{66, 183} Practically GFETs are normally composed of CVD graphene and
contain therefore defects in the lattice introduced during growth.\cite{55} Exfoliated samples are also subject to various
polymer and metal contaminations coming from the fabrication process.\cite{11} These defects and contaminations also
account for the discrepancies reported in earlier literature on pristine graphene chemical sensors.\cite{5-7} Such defect-
induced ionic response can be suppressed by passivating the graphene layer with inert aromatic molecules such as
fluorobenzene.\cite{12} As a consequence of its ideal hydrophobic surface with a very small amount (ideally zero) of
dangling bonds, such a clean GFET should be inert to the change of electrolyte compositions, and could therefore
act as a novel solid-state reference electrode that senses only the electrostatic potential in aqueous electrolytes
unless a chemo-adsorption or a physico-adsorption of charged ions is considered.\cite{184} On the contrary, by
functionalizing the GFETs with active groups, for example, with proton sensitive phenol or K⁺ sensitive crow
ethers conjugated with aromatic molecular anchor groups, a pH response up to ~49 mV/decade or a K⁺ ionic
response up to ~40 mV/dec was achieved.\cite{37} An alternative approach is to directly coat an ion-selective membrane
(ISM) on graphene surface. A recent report has demonstrated the selective detection of K⁺ ions (~8 mV/dec) over
Na⁺ ions (~0.2 mV/dec) in an electrolyte solution with an ISM composed of valinomycin, a K⁺ selective
ionophore.\cite{185}
Fig. 5 (a) Colored SEM of a graphene (purple) Hall bar device. The scale bar is given by the width of the Hall bar, which is 1 μm. Yellow color corresponds to metal electrodes evaporated on the SiO₂/Si substrate. (b) Relative changes in resistivity (Δρ/ρ, in percentage) caused by the exposure of graphene to various gases diluted at 1 ppm (NH₃: blue curve, CO: green curve, H₂O: purple curve, NO₂: red curve). Here the positive (respectively negative) changes in the Δρ/ρ curves in blue and green (purple and red, respectively) indicate electron (hole) doping. (c) Relative changes in current (ΔI/I, in percentage) of annealed exfoliated graphene (1 h at 400 °C in Ar/H₂ atmosphere) towards the detection of ammonia vapors. The lower amount of defects in the clean graphene device yields smaller changes in the sensing response, even for ammonia concentrations as high as 1000 ppm. Lower arrows indicate when the sensor device was flushed with a pure N₂ carrier gas. (d) Relative changes in current (ΔI/I, in percentage) caused by the exposure of clean graphene device (black data) and ssDNA functionalized graphene devices (Seq1 in blue: 5’-GAG TCT GTG GAG GAG GTA GTC-3’, Seq2 in red: 5’-CTT CTG TCT TGA TGT TTG TCA AAC-3’) to dimethylmethylphosphonate (DMMP) vapor at concentrations of 20, 40, 60, 80, 100, and 120 ppm. Upper arrows indicate when the sensor cell was purged with inert N₂ gas. (e) A conceptual nodal architecture of an internet of things consisting of nanomaterial sensing modulators made of wireless GFET solutions. Reprinted with permission.
Heavy metals that are notorious to health and environment (e.g. Hg, Cr, Cd, Pb) motivate the current interests in graphene heavy metal sensors.\textsuperscript{[186, 187]} Scientists have functionalized the surface of exfoliated graphene with a self-assembled monolayer of 1-octadecanethiol and applied it for Hg\textsuperscript{2+} sensing.\textsuperscript{[188]} Due to the high binding affinity of the thiol groups of 1-octadecanethiol to Hg\textsuperscript{2+}, the sensor achieved a detection limit of 10 ppm. DNAzyme aptamer decoration, on the other hand, leads to Pb\textsuperscript{2+} detection down to 37.5 ng/L with prototype device demonstrated using real blood samples.\textsuperscript{[189]} Instead of using exfoliated graphene, solution-processable rGO has also been developed for a low-cost, scalable fabrication of GFET sensors.\textsuperscript{[190]} By functionalizing the rGO with specific metal ion binding proteins or gold nanoparticle, nanomolar concentrations of Hg\textsuperscript{2+}, Cd\textsuperscript{2+}, and Pb\textsuperscript{2+} were detected.\textsuperscript{[186]} Impressive prospective has also been shared for smart graphene chemical sensors (which can be, in principle, wireless and wearable\textsuperscript{[191]}) with low maintenance cost and low energy consumption for real-time, event-based monitoring in pervasive healthcare internet-of-things applications (Fig. 5e).\textsuperscript{[192]} The selectivity of the detection, however, was not always thoroughly studied or understood in the reports representing a major challenge in the field (and for GFET biosensors in general).\textsuperscript{[193]}

4.2. GFET glucose, DNA and protein biosensors

Glucose detection has been an enduring topic since it directly reflects the metabolism condition and inspection of the chronic diabetes (the physiological concentration range of glucose detection falls in \~2-20 mM in serum).\textsuperscript{[194, 195]} Recently, the perspectives for non-invasive portable point-of-care (POC) glucose sensors imposed imperative need for biosensors with high sensitivity and reliability, as the glucose levels in body fluids (saliva, tears, urine, etc.) are much lower (\~0.01 %) than that in plasma.\textsuperscript{[196]} Conventional electrochemical glucose sensors are not sensitive enough for these applications. On the other hand, detection of glucose with the aid of electronic devices such as GFETs can reach high sensitivity down to nM concentrations (see Tab. II), which are sensitive enough for non-invasive glucose detections in body fluids. It is noteworthy that GFET glucose biosensors has also been fabricated on flexible supports such as PET (Polyethylene terephthalate)\textsuperscript{[197]} and silk fibroin\textsuperscript{[198]}. As a continuous effort to achieve flexible and cheap biosensors, recently a GFET was implemented within an 2D paper network for practical glucose detection (\~1.25 mM).\textsuperscript{[199]} Interestingly, using a PANI/Nafion-bilayer graphene modified gate electrode, researchers could also determine glucose level in saliva with a detection limit of 30 nM.\textsuperscript{[200]} We would like to note here that, despite the recent achievements in GFET glucose biosensor development, more researches
are still needed to achieve a highly sensitive and reliable platform for home use or portable application. These challenges include modifying enzyme activity for improved performance, developing methods to reliably bind them to the graphene surface, and incorporating the (functionalized) GFET into a microfluidic device.\textsuperscript{[194]}

Intrinsically, many DNAs and proteins, which contain aromatic groups, can bind onto graphene surface through $\pi-\pi$ interaction or simply by hydrophobic interactions (see Tab. I).\textsuperscript{[98]} In one of the first GFET DNA sensors, single-stranded DNA (ssDNA) was anchored on the surface of GFETs and used to detect complementary DNA strands through hybridization.\textsuperscript{[99]} It has also been demonstrated that the GFETs were capable of detecting DNA hybridizations with single-base specificity.\textsuperscript{[201]} One step further from a single device to multiplexed DNA arrays, CVD GFET sensor arrays were manufactured (Fig. 6a) and acted as both an electrophoretic electrode for site-specific DNA immobilization (not shown here) and hybridization detection down to 100 fM (Fig. 6b).\textsuperscript{[22]} GFETs were also capable of distinguishing the conductance signature upon adsorption of the four different DNA nucleobases due to the different interface dipole field.\textsuperscript{[97]} The same study concluded that the sensing of single nucleotide with graphene is feasible even without DNA amplification (amplification of DNA showed a detection limit of 50 aM using Rolling Circle Amplification\textsuperscript{[100]}). Another possibility for graphene-based DNA sensors,\textsuperscript{[202]} is to configure a graphene nanoribbon FET with a nanopore and to probe the subtle differences in the conductance as the negatively charged DNA molecules translocating through the nanopore.\textsuperscript{[203]} Interestingly, single-stranded DNA can also be used as a sensitizing agent to selectively probe various gases.\textsuperscript{[29]} Contrarily to the inert sensing behavior of clean GFETs to various gas vapor such as dimethylmethylphosphonate (DMMP, black line, Fig. 5d), ssDNA decorated GFET showed selective sensing responses to vapor of DMMP (blue and red lines indicate different sensing responses when the GFETs were functionalized with two DNA sequences).\textsuperscript{[29]} We note here that, as a functional DNA or RNA molecule selected \textit{in vitro} to bind pre-selected analytes (organic and inorganic molecules and proteins) with high affinity and specificity, aptamers also represent a versatile toolbox for producing novel graphene sensors.\textsuperscript{[171, 204, 205]}
Fig. 6 (a) Schematics and image of an 8-graphene-electrode/FET array that sits on a printed circuit board with a microfluidic channel on top. (b) 100 fM hybridization (blue) and control (green) DNA detection. The sensing signals (hybridization DNA** in blue and control DNA in green) were averaged across all eight GFETs. (c) Upper panel: illustration of rGO FET immunosensor with Pt reference electrode in the analyte solution. The rGO surface is functionalized with prostate specific antigen monoclonal antibody (PSAmAb). The zoom-in indicates the immunoreaction between the antibody (PSAmAb) and its antigen (PSA/α1-antichymotrypsin, PSA-ACT complex). Lower panel: plot of the conductance versus time for antibody (PSAmAb) functionalized rGO FET upon the binding of its antigen (a PSA-ACT complex). Experiments were carried in a PBS buffer solution at pH=7.4. The black arrow indicates the injection of the antigen (PSA-ACT complex) at different concentrations.

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GFETs have also been widely reported for protein detection. In an earlier study, bovine serum albumin (BSA) nonspecifically adsorbed on a graphene surface can be detected at 300 pM concentration.\[10\] Separately, selective detection of immunoglobulin E (IgE) can be realized by functionalizing graphene with aptamers (through probing the charges the IgE brings as it binds to the aptamers).\[171\] One of the important expectations/outcomes of a highly sensitive and selective bioGFET is to analyze biomarkers for especially point-of-care applications.\[65-67\] As an example, femtomolars of prostate specific antigen/α1-antichymotrypsin (PSA-ACT) – a complex biomarker in prostate cancer diagnosis – could be detected using a rGO FET (Fig. 6c, lower panel) by functionalizing the graphene surface with PSA monoclonal antibody (PSAmAb) (Fig. 6c, upper panel).\[78\] Attomolar level detections
have also been reported occasionally\textsuperscript{205} but such significantly improved sensitivities were not always consistent with the more generally observed nM-pM detection limit,\textsuperscript{66, 67} suggesting that more dedicated efforts are still needed to improve the reliability and the reproducibility of the sensing response.\textsuperscript{206} This brings us back to some of the fundamental issues associated with graphene-based BioFETs (and BioFETs in general) as eventually, after carefully designing and controlling every steps of a GFET, we will be looking at the Debye screening effects as an obstacle to achieve ultimate detection of a relatively large biomolecule in physiological conditions as previously discussed in Section 2.5 and will be further reviewed in the next Section 5.2. Alternatively, the detection of biomolecules can also be achieved by monitoring pH changes during adsorption, thus circumventing the Debye screening effects as proton is negligibly small.\textsuperscript{207} Along this line, GFETs were applied as pH sensors to detect alanine aminotransferase (ALT) in the concentration range of 10-100 unit/L by monitoring the generation of protons during the enzymatic reaction between L-alanine/α-ketoglutarate and ALT.\textsuperscript{208}

### 4.3. GFET biological cellular sensors

Recently, as a part of the Europe’s Graphene Flagship – a €1 billion project aims to bring graphene from innovative laboratory researches into commercial applications, scientists interfaced graphene to neurons directly, while retaining the integrity of these vital nerve cells.\textsuperscript{148} In fact, stimulating and recording extracellular potentials (or even intracellular potential using branched transistors\textsuperscript{209}) from neurons is one of the hallmark of modern bioelectronics. Graphene can serve not only as conductive electrodes to transduce stimuli into the cells, but also as the conductive channel of GFETs to monitor the presence and activity of the cells.\textsuperscript{99} Fig. 7a illustrates a cell-transistor measurement,\textsuperscript{68} where a cell is located on the graphene surface. A constant bias voltage is applied to the drain and source electrodes (in gold yellow), bridged by a graphene conductive channel (in pink). The current in the graphene channel is amplified and monitored in real time. Any local electrochemical potential change triggered by the action potential of the cell leads to a modulation of the source-drain current in graphene (due to the field effect). A separate study combined GFETs (exfoliated graphene) and silicon nanowire FETs to probe single electrogenic cardiomyocyte cell (Fig. 7b).\textsuperscript{176} The GFETs yielded well-defined current peaks (extracellular signals) with signal-to-noise ratio (SNR) routinely above four, which is comparable to that of the nanowire FETs (Fig. 7c).\textsuperscript{176} Narrow GFETs (∼2 um×3 um) exhibit similar peak-to-peak widths as the nanowireFET (∼100 times smaller per area). But GFET devices with large size (∼20 um×10 um) detect an average of the extracellular...
potential from beating cells and yield a broadened peak-to-peak signal width.

Arrays of GFET have been developed to monitor tissue-like specimens.\textsuperscript{[210]} Densely packed cardiomyocyte-like HL-1 cells were cultured on the surface of graphene arrays (a fluorescence image of the cells is shown in Fig. 7d). The propagation of the action potentials across the beating cellular network is monitored by recording the current flowing through the transistor array (Fig. 7e). In the current trace, spikes from the different GFETs depict the variations in the graphene-cell coupling and the propagation of the action potentials across the HL-1 cell network. Furthermore, these GFETs exhibit a SNR better than ten. Even at its early stage of development, such SNR performance equals (or even surpasses) that of well-established techniques like the microelectrode arrays (MEAs) and the planarFET\textsuperscript{[211]} and nanowireFET\textsuperscript{[176]}.

In order to provide a control over the specific voltage-gated ion-channels in the cell membrane\textsuperscript{[212]} (and thus the action potential of the cell), patch-clamping experiments were combined with GFETs (Fig. 7a), where a patch pipette containing an inner electrode was manually introduced into the inner part of a single HEK-293 cell. Because the HEK-293 cell were genetically modified so that the membrane contains only K$^+$ channels,\textsuperscript{[211]} the opening and closing of these ion channels could be unambiguously identified by monitoring the current across the membrane with the patch electrodes.\textsuperscript{[68]} Simultaneously, signals from the GFET could be attributed to these K$^+$ channels and very good SNR (up to fifty) could be achieved by repeating the same process multiple times.\textsuperscript{[68]} Besides the action potential, GFET can also measure the electromechanical coupling between rGO microsheets and – for example – yeast cells (Fig. 7f).\textsuperscript{[147]} The flexible rGO layer responses electrically to the change in cell volume when exposed to different alcohols due to a strong mechanical coupling. By monitoring the dynamic electrical response of rGO, it was possible to differentiate between ethanol, 2-propanol, and water, each inducing different physiological stress response on the cell.

Based on the current state-of-the-art of GFET cellular sensors, graphene and graphene-related materials have confirmed their suitability for monitoring the activity of cells with excellent SNR (both electrically and mechanically). Looking ahead, new advancements could reside in the development of flexible GFET cellular sensors,\textsuperscript{[214]} by combining the outstanding electronic performances of GFET with the high flexibility of graphene.\textsuperscript{[215]} In such a flexible bioelectronic platform, individual cells in a network can be addressed via electrical interfaces, which could potentially lead to advanced learning circuits, neuron-implants, and neuroprosthesis that
could potentially replace damaged nervous tissue for treating brain and paralysis diseases.\cite{148}

![Image](https://example.com/image1)

**Fig. 7** (a) Schematic of a single cell coupled to a GFET combined with a patch-clamp electrode setup. (b) Top: illustration of two sensors, one incorporating a SiNW and a second using graphene as the sensing element. Bottom: illustration of the chip design incorporating graphene and SiNW devices, highlighting the relative size of a cardiomyocyte cell with respect to the device dimensions. (c) The representative detection peaks in blue were recorded at the p-type polarity of the GFET, red peaks represent recorded traces at the n-type device polarity, and the green peak was recorded near the CNP of the GFET. (d) A fluorescent optical image of a GFET array with stained cells. Scale bar: 100 μm. (e) Time-dependent current recordings of eight transistors from one array (marked from T1 to T16). (f) Conductance versus time plots of a rGO FET upon exposure of the (rGO covered) cells to ethanol and 2-propanol solutions. Inset: AFM image of the surface of a cell deposited between Au electrodes on a silicon dioxide chip. Reprinted with permission.

### 4.4. Graphene-based electrochemical (GEC) biosensors

In liquid-gated GFET biosensors, the electrical current is confined transversely in the graphene conductive channel. Any electrochemical current vertically flowing between the graphene channel and the liquid gate (through the electrolyte solution), is regarded as a spurious signal and limits the performances of gate controlled GFET devices.\cite{12} This electrochemical current is – however – at the basis of graphene electrochemical (GEC) biosensors, which are complementary to GFETs.\cite{216} In this regard, it is necessary to understand the construction as well as the
working principle of a GEC sensor, in order to fully appreciate the operation of a GFET. Specifically, the sensing principle of a GEC sensor roots on the electrochemical transfer current between the redox active biomolecules in the solution-phase and graphene surface.

Similarly to GFETs, the GEC uses the surface of graphene as the major sensing element. Until now, the majority of GECs uses graphene dispersions (usually nanosheets of chemically functionalized graphene) deposited on conductive electrodes.\textsuperscript{217, 218} These graphene dispersions with large surface to volume ratio – in contrast with mono- or bilayer graphene sheets employed in GFETs – contain more defective areas. These defects enhance the density of electronic states (DOS) of graphene dispersions, which favors the electron transfer between the graphene materials and the redox biomolecules, and thus yielding a higher sensitivity.\textsuperscript{219} For example, reduced graphene nanowalls (rGNW) with large amount of sharp edges have been deposited vertically via electrophoresis on a graphite electrode to detect double-stranded DNA (dsDNA) with an impressively wide detection concentration range of 0.1 fM – 10 mM.\textsuperscript{218}

The sensitivity of the abovementioned GEC biosensors resides in the defects of graphene. Functionalizations of these defects with electrochemical catalysts lead to further improved sensitivity and selectivity for the detection of a wide range of molecules, namely glucose,\textsuperscript{220} cholesterol,\textsuperscript{221} DNA,\textsuperscript{222, 223} proteins,\textsuperscript{224} and even living cells.\textsuperscript{103, 225} To functionalize graphene, most typical catalysts are composed of enzymes,\textsuperscript{226} metal nanoparticles,\textsuperscript{227} and polymers,\textsuperscript{228} to name a few. In fact, to a large extent the functionalization of a GEC is similar to that of a GFET. Advantageously, covalent functionalization often results in dramatically enhanced DOS in graphene facilitating higher electron transfer rate.\textsuperscript{219} Non-covalent functionalization, however, has the advantage to retain the excellent electrical properties of graphene, and, to a certain extent, limit the possible charge transfer across the interface, and thus favoring the GFET biosensors. Drop-casting deposition\textsuperscript{223} is one of the most widely adopted methodologies to fabricate GEC biosensors with functionalized graphene dispersions. Such graphene dispersions, however, usually contain a mixture of mono-, bi-, few layer graphene flakes with uncontrolled and even unknown defect, impurities, or chemical functionalities. In order to unambiguously address the electrochemical properties of graphene, the difference in the electrochemical activity of the edge and the basal plane of graphene have been carefully studied (Fig. 8a).\textsuperscript{229} Graphene edges (with current density $j = 0.11$ A cm$^{-2}$) exhibit larger electrocatalytic properties, while the basal plane ($j = 2.2 \times 10^{-4}$ A cm$^{-2}$) is relatively inert (Fig. 8b). Previous studies carried out on
clean graphene monolayer with a well-defined surface area, on free-standing graphene samples over a nanopore, and on graphene and graphite step edges using scanning electrochemical microscopy (SECM), confirmed this trend that edges are electrochemically more active than the basal plane. In combination with Raman spectroscopy (Fig. 8c), SECM is able to quantitatively correlate the defect density of graphene with its localized electrochemical activity (Fig. 8d), providing new possibilities to systematically study the electrochemical properties of graphene. The correlation indicates that the electrochemical activity first increases with the defect density (in line with earlier reported higher reactivity for covalent derivatization), and then decreases when ‘defective’ graphene sheet loses its structure integrity (i.e., presumably when the aromaticity of graphene is totally lost). As a perspective, a GFET biosensor can in principle be combined with a GEC biosensor we described here in a same device, and thus providing a fully complementary sensing platform to study both the electrostatic charge of the biomolecules but also the charge transfer during redox reaction at the graphene surface. Such device configuration has already been realized in organic electrochemical transistors with graphene-modified gate electrodes, which was proved to significantly improve the selectivity of the organic electrochemical transistors for dopamine detection.

![Fig. 8](image)

**Fig. 8** (a) An illustration of edge-based (left) and basal plane-based (right) CVD graphene. Epoxy resin (ER), a non-conducting pinhole-free polymer, is employed here to coat graphene and only expose the surface of interest. (b) Cyclic voltammetry studies
demonstrated that the current density on edge electrode (0.11 A cm\(^{-2}\)) is 500 times higher than that on the basal plane one (2.2 \times 10^4 A cm\(^{-2}\)). (c) Raman mapping of the D band of the defective graphene patterns (light squares) induced by Ar\(^+\) irradiation. Window size: 500 µm by 500 µm. (d) Scanning electrochemical microscopy (SECM) of the same defective graphene patterns with a tip potential of 0.4 V and a substrate potential of 0.11 V. Window size: 500 µm by 500 µm. Square F with medium defect density as tested by Raman spectroscopy exhibits the highest electrochemical activity. Reprinted with permission.

5. Perspectives and conclusions

GFET is a young member of the huge family of current biosensors based on optical transduction and/or electrical transduction principles, but it has already opened a totally new, very promising range of options for biochemical sensing. Indeed, the reliability and reproducibility of GFET biosensors were not always thoroughly studied or understood in the reports, representing a major challenge in the field\[193\] that, in principle, could be solved via reliable processing of device fabrication and rational design of graphene surface functionalizations. We believe that the future of GFET based biosensor exploration should focus on the unique physical and chemical properties that graphene offers,\[235\] in the direction to improve even further its sensitivity with ever-demanding reliability and reproducibility. In the following, we will have an in-depth look at the benefit by reducing possible competing sensing reactions to preserve the highest possible biological signal at graphene surface. Particularly, we will discuss current progresses on high frequency biosensors based on nanostructures including graphene materials, which suggest that the Debye length limitations could be overcome in physiological conditions without any special design or engineering of the receptor molecules and the sensor environments. We expect these perspectives will prompt GFET’s future development with potential to revolutionize the fields ranging from neuronal sensing to point-of-care medical diagnosis.\[65-67, 192\]

5.1. Graphene as a chemically inert surface: towards an ultimate biosensor

In 2011, Ion Torrent by Life Technologies (USA) directly translated chemically encoded information in genomes (A, C, G, T) into digital information (0, 1) on a semiconductor chip, and thus being able to commercialize the first low-cost integrated semiconductor device based on Si technology for non-optical genome (DNA) sequencing.\[207\] The DNA sequencing is achieved by detecting the pH changes induced by protons that are released when nucleotides (dNTP) are incorporated on the growing DNA strands. In fact, pH sensors are the only ion-sensitive
FET sensors that have been successfully commercialized due to the highly sensitive (~60 mV/pH) and selective nature of the highly abundant hydroxyl (–OH) terminal groups on the oxide surface (SiO₂, Al₂O₃, HfO₂, Ta₂O₅, etc.) towards protons.[42] Although Si ion-sensitive FETs can also probe and detect biomolecules directly,[236] no commercial biological ion-sensitive FETs has been released so far. In fact: i) such devices are more capable of detecting small molecules such as protons, as the Debye screening effect limits the charge detection of large biomolecules (details will be discussed in Section 5); ii) the very high density of the hydroxyl (–OH) groups diminish the sensing response of the Si ion-sensitive FET to biomolecules. That is, upon the binding of target biomolecules onto the receptors immobilized on the surface of a Si ion-sensitive FET, the protonation (–OH₂⁺) or deprotonation (–O⁻) of the nearby unpassivated –OH groups[42] (a full passivation of the surface –OH groups by receptors is difficult[237]) will buffer and significantly screen/hinder the sensing response of the Si ion-sensitive FET to the charged biomolecules.[236] In this regard, beside the above discussed well-known advantages (such as high mobility, low intrinsic electrical noise, large surface to volume ratio and stability) the fact that graphene possesses a surface that is free of dangling bonds (–OH groups, for example), represents another significant advantage and unprecedented opportunities over Si ion-sensitive FETs for biosensing applications.

This screening/interference effect can be understood by considering the following iterative sensing steps: i) positively charged target biomolecules attaching to the receptors cause a change in the total surface charge: +ΔQ₀ (biosensing signal); ii) the change in the total surface charge initiates a redistribution of the proton concentration near the sensor surface due to Boltzmann distribution in the electrolyte environment;[42] iii) the change in the proton concentration at the surface will, in turn, induce a negative change in the surface charge -ΔQ₀ due to the protonation/deprotonation of the –OH groups, which will compensate the aforementioned sensing signal +ΔQ₀. In an extreme case, this compensation will be complete if the sensor surface has a Nernstian pH response[238] (indicating very high density of unpassivated –OH groups). Consequently, there will be no sensing response because any changes in the surface charge +ΔQ₀ due to positively charged target biomolecules attached to surface immobilized receptors are totally screened by the protonation/deprotonation reactions. In fact, a reduced biosensing signal can be measured if the compensation is not complete.[239] In our opinions, this screening effect has caused many problems for FET-type of biosensing applications (sometimes even without noticing), where the surface functionalization started with a surface of very high –OH group density. In the contrary, the highest
sensitivity is reached, if the density of the surface –OH groups is zero (except if one aims to sense the pH). This is the case of ideal graphene. Hence, if graphene is used as the sensing surface and the conducting channel in an ion-sensitive FET at the same time, an ultimate sensor could be realized.

5.2. Overcoming the Debye length limitations with radio-frequency (RF)-operated GFETs

GFETs are primarily sensitive to the charges carried by the biomolecules adsorbed on top of the graphene surface. In previous Section 2.5, we reviewed that FET based biosensors could suffer from the ionic screening due to mobile ions present in the solution, known as Debye screening effect.[73] As the charges are heavily screened, they can hardly be detected if the distance between the charged biomolecules and graphene surface exceeds several times the Debye length, which is about 0.7 nm at physiological conditions. Possible routes to circumvent the Debye screening effect include short antibody design, porous polymer incorporation, and ex situ measurement in low ionic strength buffers (see Section 2.5).[74-77, 80] These approaches, however, also impose limitations on the biodetection and it is highly desirable to develop a straightforward methods to overcome the Debye screening:[46] 1. without any special design or engineering of the receptor molecules and the sensor environments, and 2. in physiological conditions to facilitate in-situ, real-time biosensing.

Fig. 9 (a) The Debye screening effect dominates at DC and frequencies lower than ~10 MHz. At higher frequencies, the electrolytes behave as dielectrics. (b) Relative changes in mixing current (ΔI_mix/I_{mix}, in percentage) of a carbon nanotube-based streptavidin-biotin sensor as a function of frequency at 100 mM NaCl solution. Reprinted with permission.

Theoretically, improved sensitivity is expected at high frequencies using a measuring strategy that overcomes the ionic screening effect. This improvement is because at RF/microwave frequencies the ions in the electrolyte lag behind the alternating current (ac) electric field due to the viscosity of the solution.[40] As a result, the Debye screening is cancelled and the buffer solution can be regarded as a pure dielectric at high frequencies (much larger
than 10 MHz, see Fig. 9a).\textsuperscript{[40]} And hence the displacement of water from the interface by a lower dielectric constant such as a biomolecule can be detected/transduced as the output signal of the RF sensors, which ultimately relates to the chemical structure (i.e., dipole moment) of the biomolecule.\textsuperscript{[46]} Recently, in an attempt to detect beyond the Debye length, carbon nanotube sensors were operated at frequencies up to $\sim$ 10 MHz.\textsuperscript{[46]} The sensing response, defined as the relative change of the measured mixing current $\Delta I_{\text{mix}}/I_{\text{mix}}$ of the sensor, increases for increasing the measurement frequencies (up to 10 MHz, Fig. 9b, blue arrow) due to a continuous reduction of the Debye screening effect. However, an unexpected drop in the sensing response at 30 MHz was observed (Fig. 9b, red arrow). In fact, at frequency smaller than 10 MHz the ions in the aqueous solution (at physiological conditions) can still follow the electrical signal.\textsuperscript{[40]} As a result, the charged biomolecules are still screened (at least partially) by the movable ions in the buffer solutions (Fig. 9a). In order to unambiguously test whether GFET operated at high frequency can overcome the Debye screening limitation, further research at frequencies above 10 MHz would still be highly desired.

In fact, owing to its exceptional high mobilities, graphene is potentially suited for high-frequency applications.\textsuperscript{[15]} For instance, high-frequency GFETs with an intrinsic cut-off frequency of above 300 GHz have been demonstrated, which outperforms the best silicon FETs with similar gate lengths.\textsuperscript{[240]} However, our knowledge of the high-frequency (much higher than 10 MHz) properties of GFETs in the presence of the electrolyte (in direct contact with the graphene layer) is very limited. As an attempt to forward our understanding of the RF properties of graphene, especially with regards to sensing in a liquid environment, the operation of an electrolyte-gated GFET at RF/microwave frequencies ($\sim$2-4 GHz) has been achieved in a recent study.\textsuperscript{[241]} Owing to the wide bandwidth, the graphene RF device also enables ultrafast measurements at nanosecond time-resolved.\textsuperscript{[241]} We note here that AC electric field also exerts great influences on the fluid and results in micro-nano electrokinetic phenomena like electroosmosis and especially dielectrophoresis,\textsuperscript{[242]} which could, in principle, be adopted to manipulate, sort, and concentrate different types of nanoparticles and biomolecules at the strongest field range to enhance further the detection limit. Indeed, the development of RF sensors is still in the early stage, but already reveals great potential for a wide range of biochemical sensing applications.\textsuperscript{[243]} Sincerely, we hope that the perspective of RF graphene biosensors will open up new directions in research in the biomedical, environmental, and other high performance sensor fields.\textsuperscript{[192]}
To conclude, this article comprehensively reviews recent research efforts devoted to understanding the operation mechanisms of GFETs in electrolytic environments, and to functionalizing the graphene surface with particular recognition moieties to unlock its sensitivity potential. We provide a timely overview on the recent developments of gas sensors, protein and DNA biosensors, and biological cellular sensors, using the surface of graphene as the sensing element. We are convinced that graphene biochemical sensors hold great promise to meet the increasing demands on the sensitivity, especially by the recent progresses on operating GFETs at high frequencies suggesting that Debye screening can be overcome.

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